



# IEEE SW Test Workshop

Semiconductor Wafer Test Workshop

June 9 - 12, 2013 | San Diego, California

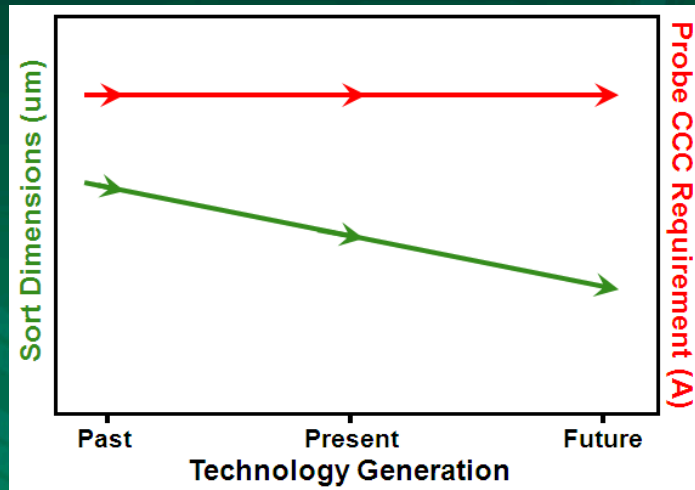
## Beyond ISMI: Electric Current Capacity of Vertical Probes Under Pulses and Transient Signals



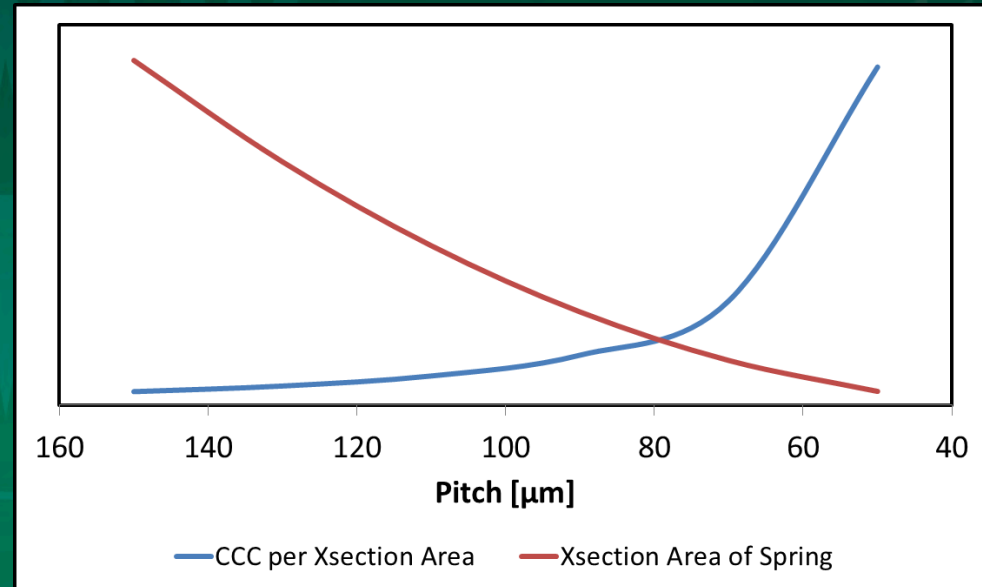
Kevin Hughes

FormFactor, Inc.

# Semiconductor Trends Influencing CCC



\* Zeman SWTW2010 "A New Methodology for Assessing the Current Carrying Capability of Probes used at Sort"

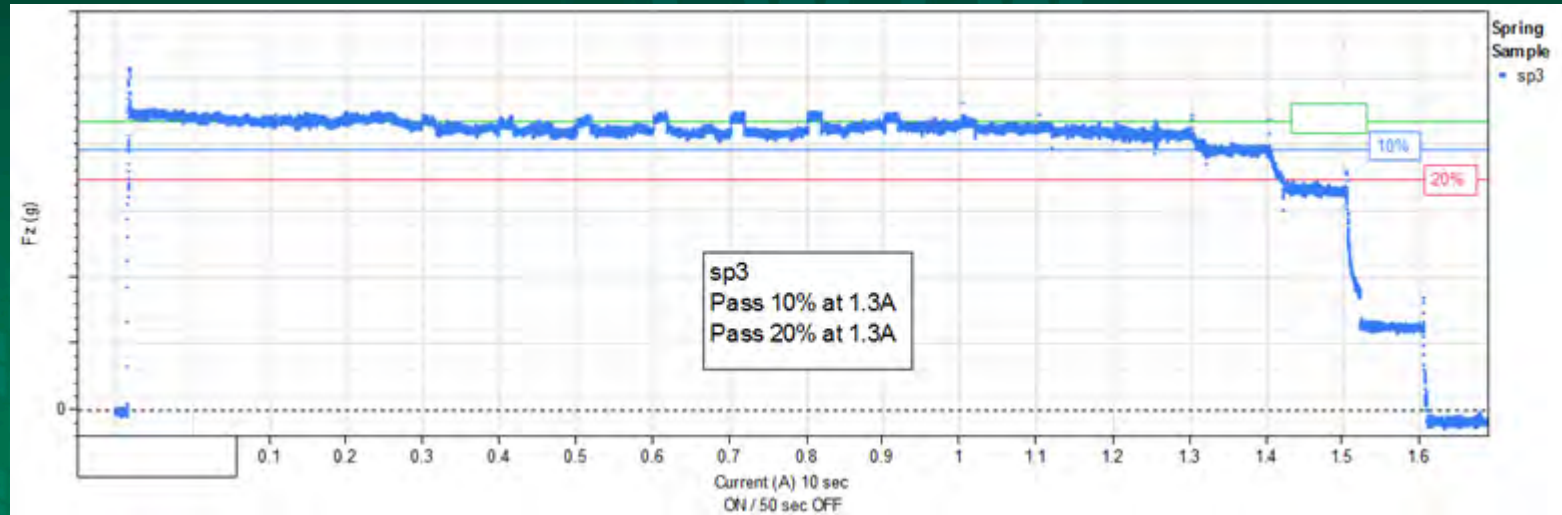


- **Keeping CCC for < 100μm Pitch is really hard**
- **Need to design efficiently to keep pace**
  - Requires smarter probe design
  - Requires smarter communication between test customers & suppliers



# How are Things Done Today?

- ISMI CCC Test standard:



Presented at SWTW in 2009, the goal of the ISMI guideline is “...to minimize variability in the measurement of this critical parameter... With a focus on reproducible measurements, this guideline provides CCC ratings that are inherently different from what a user will see in a production environment.”\*

- Test suppliers/customers develop internal “rules of thumb” to convert intended chip current into equivalent ISMI rating.

\* Daniels, E Boyd, 2009. *ISMI Probe Council Current Carrying Capability Measurement Standard*. San Diego, CA, June 7-10 2009, IEEE SW Test Workshop.





# Influence of CCC on Probe Design

## Design "Points"



- Because the physics involved are nonlinear and start to "kick in" <math>< 100\mu\text{m}</math> pitch, the rules-of-thumb will become increasingly less useful.
- Need to elevate the level of discussion and understanding with regard to CCC between test suppliers and customers.
- Probe design is all about proper allocation of design "points"



CCC



Force\K-value



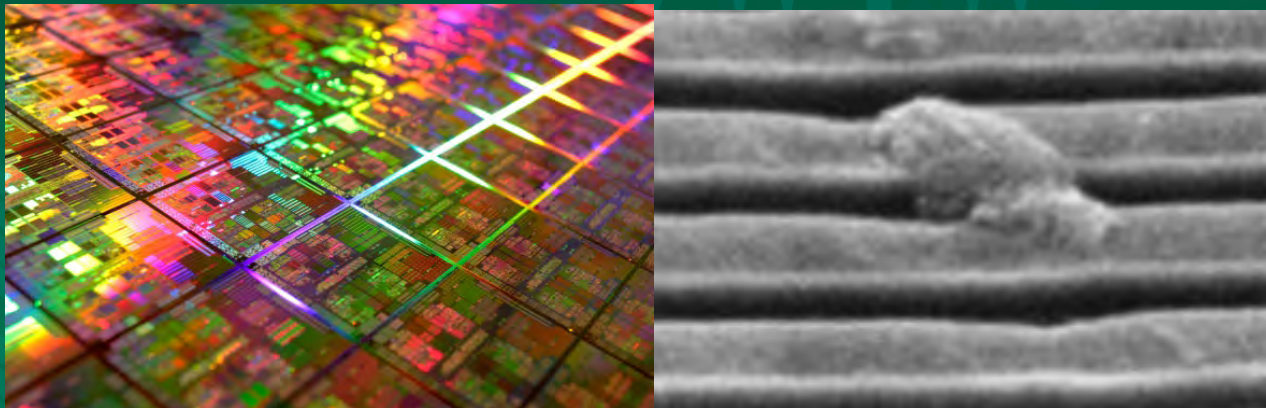
Max OT

- Under-performing CCC = very bad, burnt probes
- Over-performing = still bad, comes at cost of probe stiffness & max OT



# Objectives & Goals

- **Root cause of probe burns often lies in wafer-level defects causing unpredictable surges in current\***



*\* Zeman SWTW2010 “A New Methodology for Assessing the Current Carrying Capability of Probes used at Sort”*

- **Goal is to understand & share learning on how CCC behaves against the full spectrum of square-wave signals.**
  - Present Day: Develop & verify a multiphysics model that can handle any type of specified signal.
  - Long Term: Construct a full multiphysics probe card model to convert Chip Requirements --> Spring Design --> ISMI Rating

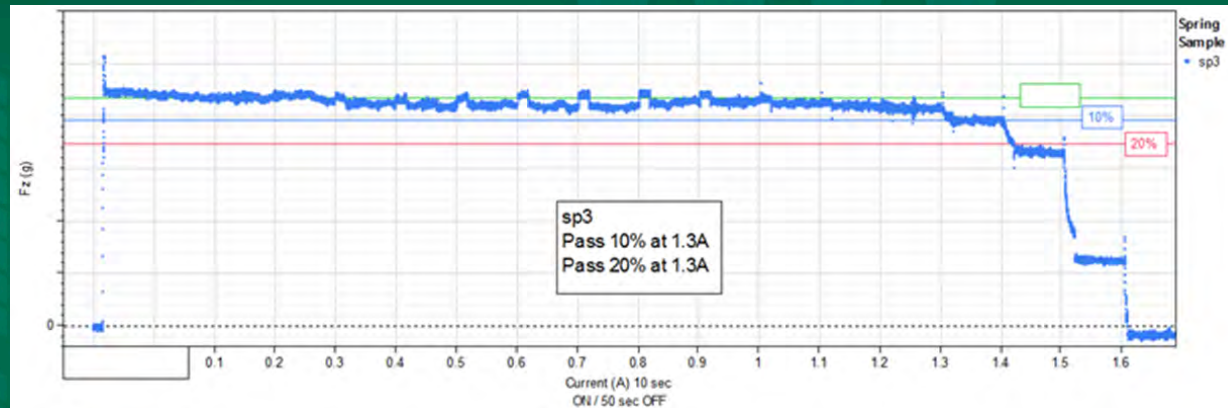




# Failure Modes: DC vs Square-Wave

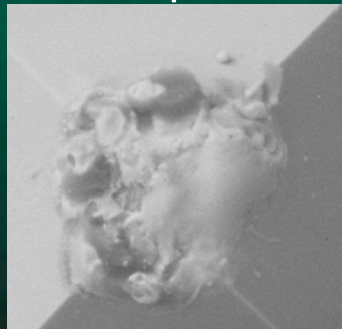
- **DC Failure Mode:**

- Reduction in contact force from heating in high stress locations of spring

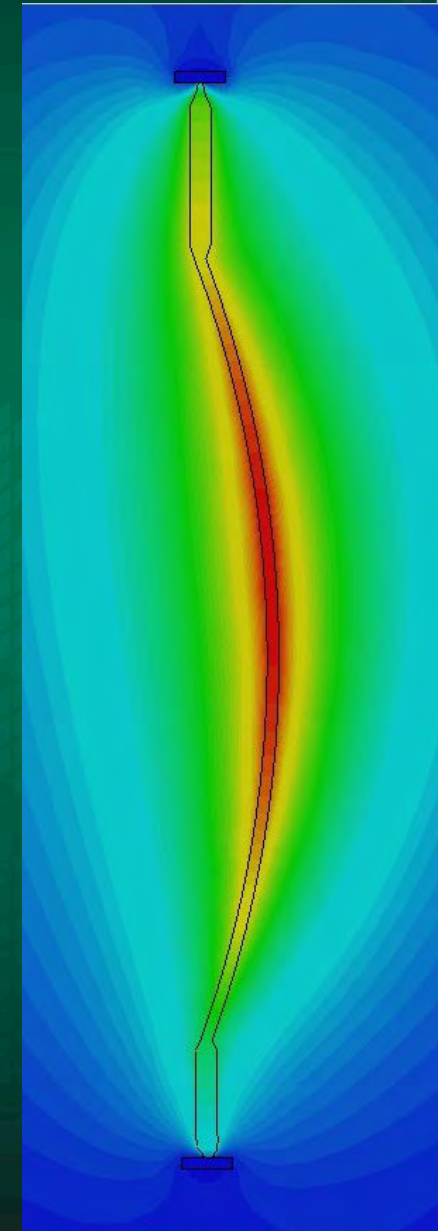


- **Square-Wave Failure Modes:**

- Long Duration Pulse = Reduction in contact force
- Short Duration Pulse = Tip melting



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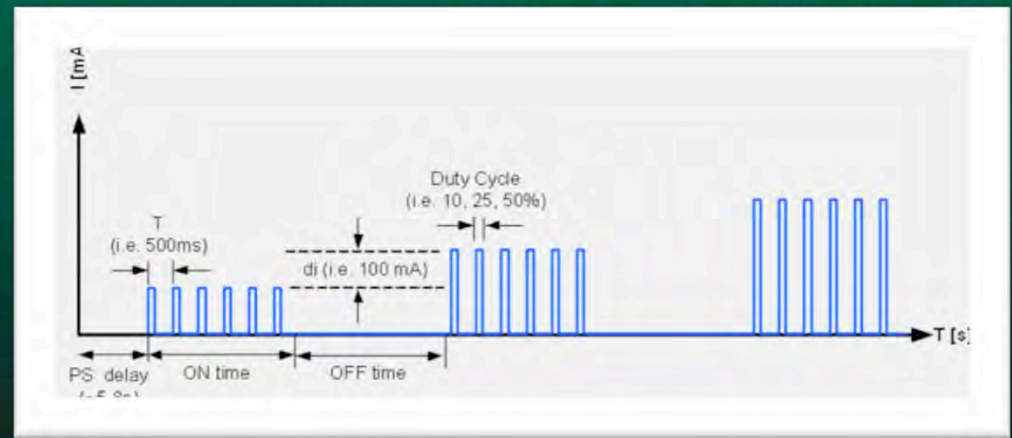


# Overview of Test Methods & Procedure

- **Multiphysics Simulation Calibration Steps:**

- Using ANSYS & Solidworks Flow Simulation, built a model that matched ISMI testing for all our probe products. This gave insight into temp rise/fall times.
- Ran experiment for CCC vs Pulse ON length
- Refined model to match all test cases for the same contact constraints
- Used model to generate CCC behavior for any specified signal

- **Quantified this behavior for one of our probe products for presentation today.  $CCC_{ISMI} = 0.8A$**



# Results Overview

- **Important Insight:**

- Probe behavior most easily understood based on the relationship between probe cooling and OFF duration between pulses.

- **For the probe presented:**

- Time to cool  $\approx 100\text{ms}$  ( $\tau = 25\text{ms}$ )

- **Can classify any square wave into 3 groups:**

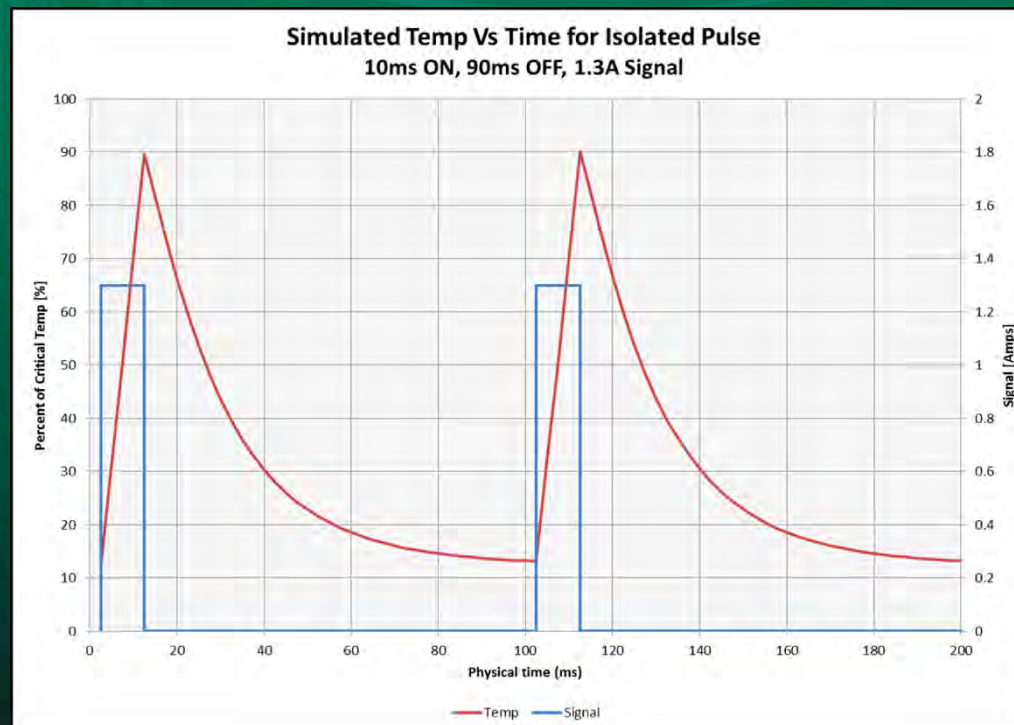
- Isolated Pulses: Time between events is long enough that the probe carries no significant heat between pulses. ( $f \leq 10 \text{ Hz}$ ,  $T \geq 100\text{ms}$ )
- Hi-Speed Signals: Time between events is short enough that the probe experiences only small  $\Delta T$  between pulses. ( $f \geq 1 \text{ kHz}$ ,  $T \leq 1\text{ms}$ )
- Intermediate Signals: Consists of the remainder. Time between events is such that the probe experiences large  $\Delta T$  & carries residual heat between pulses. ( $f = 10 \text{ Hz} - 1 \text{ kHz}$ ,  $T = 100\text{ms} - 1\text{ms}$ )





# Isolated Pulses: Definition

- **Definition:**
  - Time between events is long enough that the probe carries no significant heat between pulses. ( $f \leq 10 \text{ Hz}$ ,  $T \geq 100 \text{ ms}$ )
  - Analogous to capacitor discharge or not fully powering down between touchdowns (“hot stepping”)
- **Most important signal class to understand in order to prevent burnt probes**

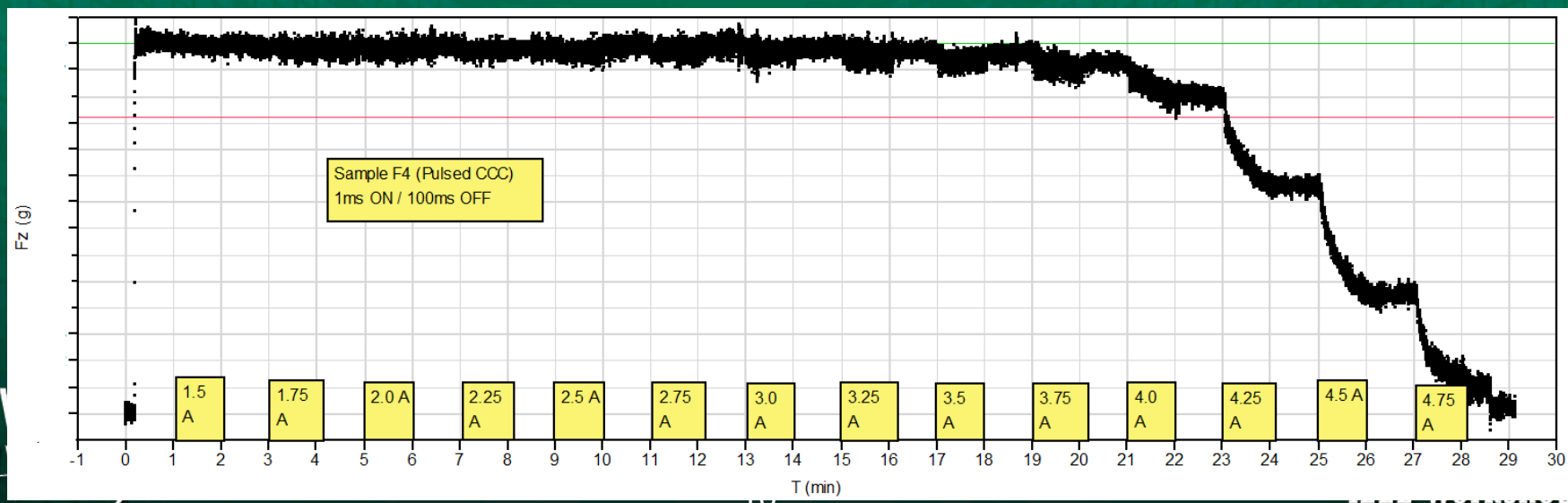


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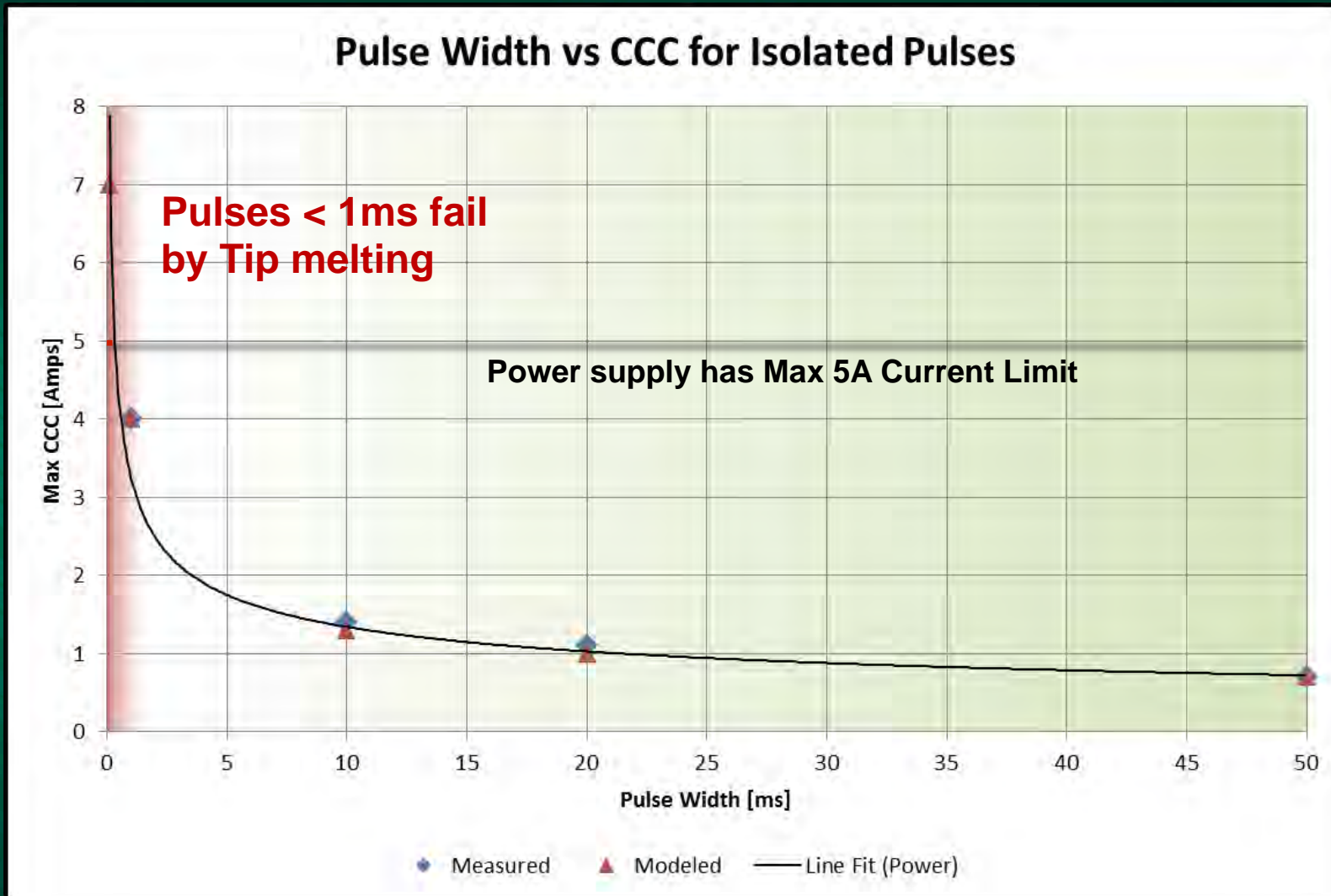
# Isolated Pulses: Procedure

- **Experimentally measured CCC for Isolated Pulses:**

- ON Duration: 20ms, 10ms, 1ms, 0.1ms
- OFF Duration: 100ms
- Procedure:
  - Signal Run for 1min → Check Force → Increase Current → Repeat Until Failure
- Probe subjected to ~545 pulses at each current level before re-checking force and increasing current further



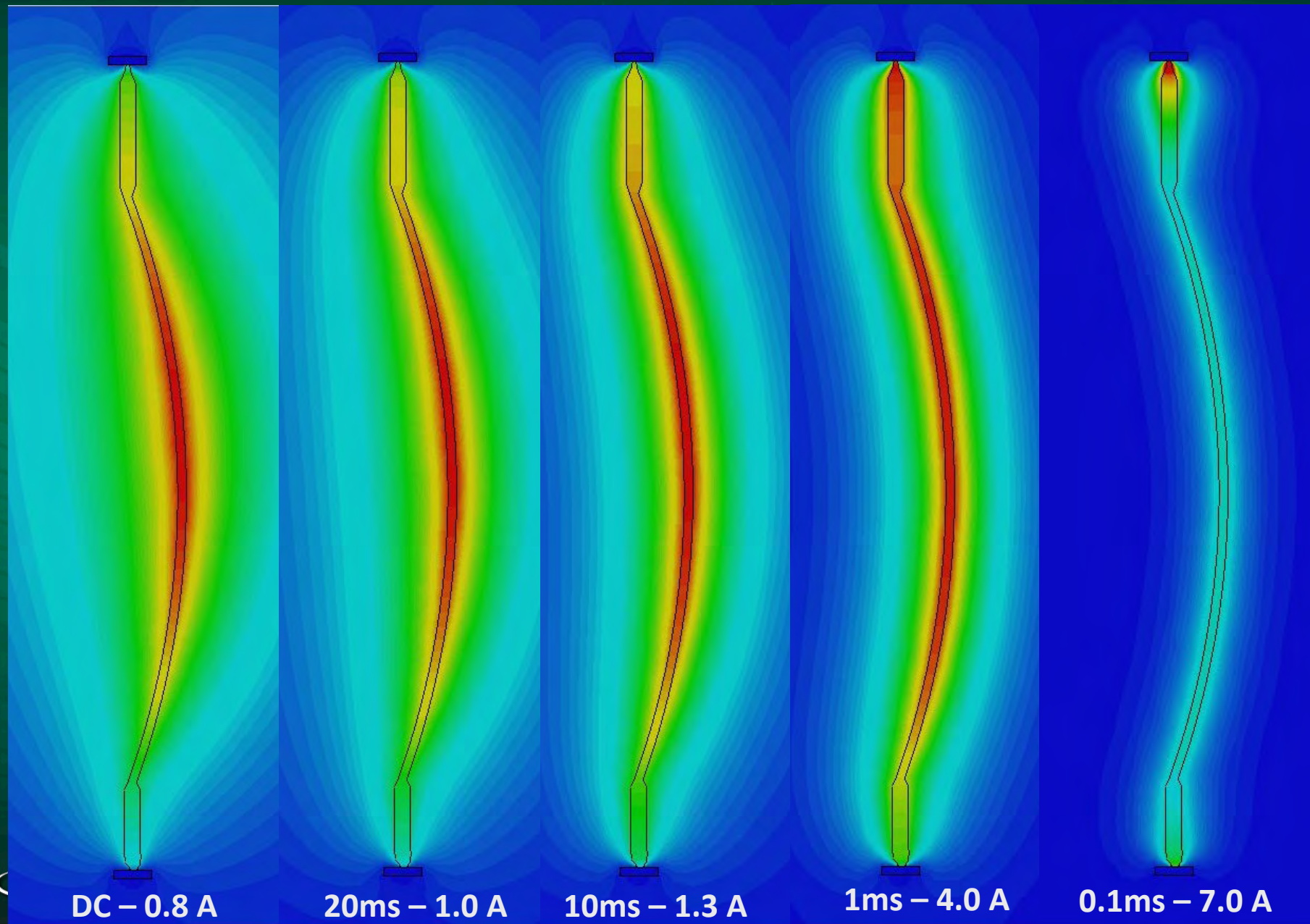
# Isolated Pulses: Results



- Probes survived 550 pulses at 4.0 A, if duration is  $\leq 1$ ms.
- 400% increase in CCC over ISMI rating of that product!
- Starting at  $\sim 5.0$  A, 0.1ms pulse we start seeing melted tips

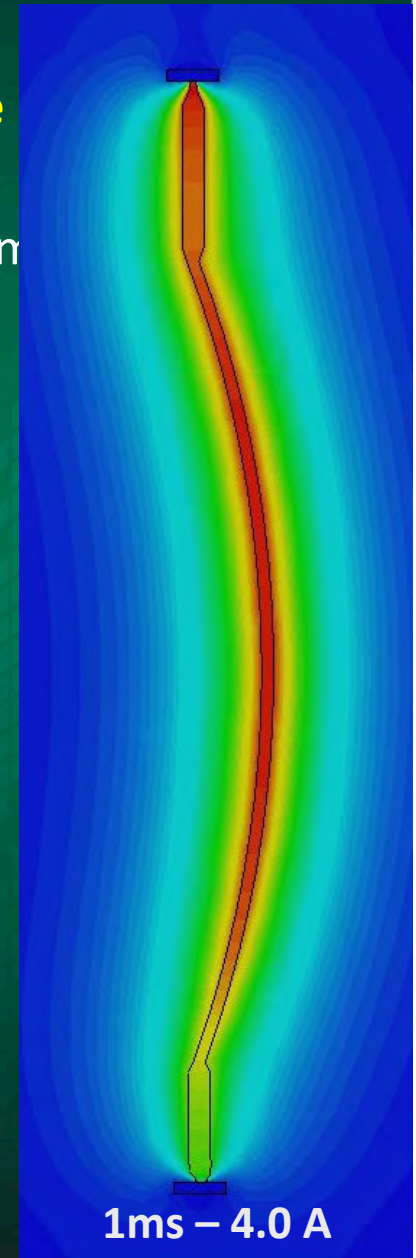


# Isolated Pulses: Behavior



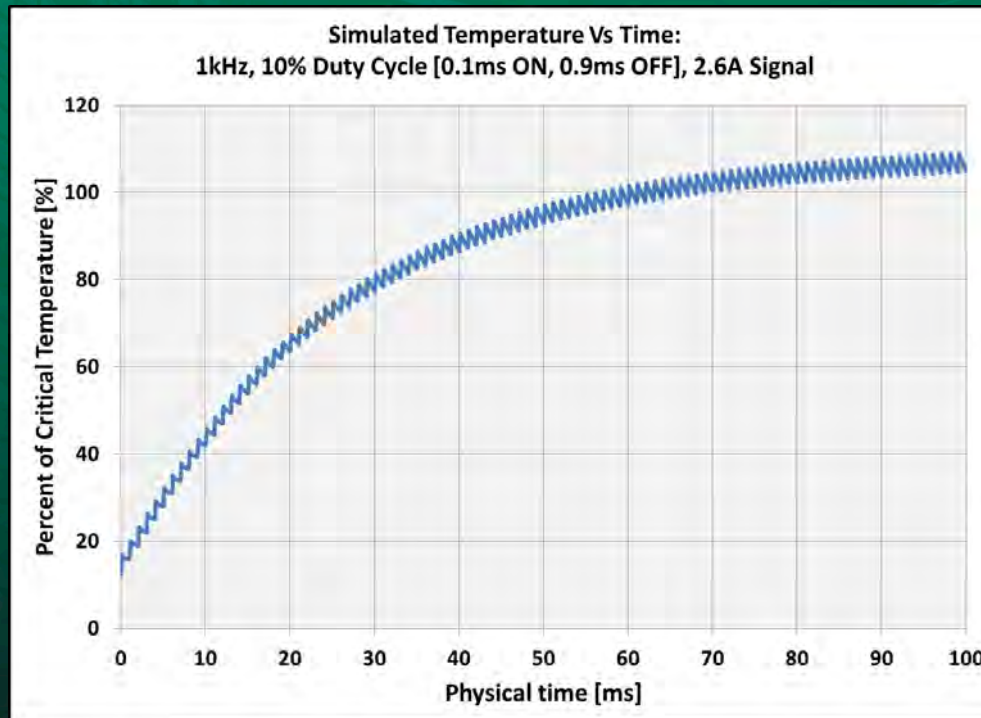
# Isolated Pulses: Comments

- **There exists a practical limit on CCC for isolated pulses where max current can no longer be increased by a decrease in pulse length due to instantaneous melting at the tip.**
  - For the product shown this practical limit is  $\sim 5.0$  A for a 0.1ms pulse
- **There exists a transition point where the probe failure mechanism changes from loss of contact force to tip melting.**
  - For the product shown here that point is a 4.0 A, 1ms duration pulse.
- **Dominating factors:**
  - Pulse Width & Spring Design
- **Isolated pulses can be successfully predicted and understood using a multiphysics simulation software**



# Hi-Speed Signals: Definition

- **Definition:**
  - Time between events is short enough that the probe experiences only small  $\Delta T$  between pulses. ( $f \geq 1 \text{ kHz}$ ,  $T \leq 1 \text{ ms}$ )
  - Analogous to a fast logic signal
- **Hi-Speed signals represent the most common intended signals**
  - Understanding CCC behavior for signals operating at speeds  $> 1 \text{ kHz}$  will help tailor probe designs used at these locations.



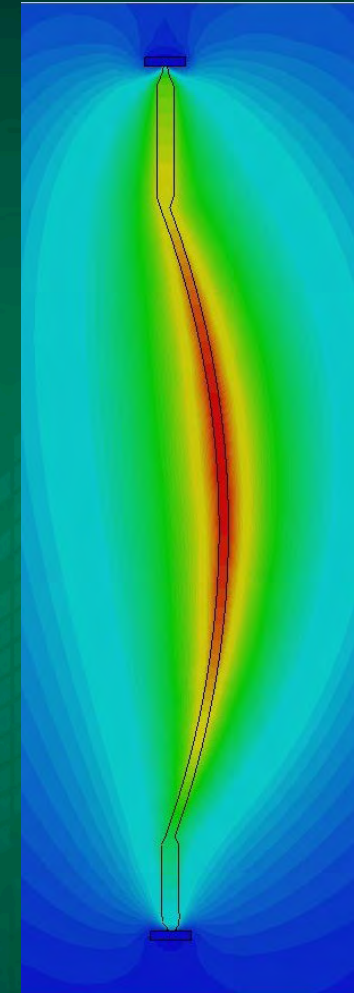
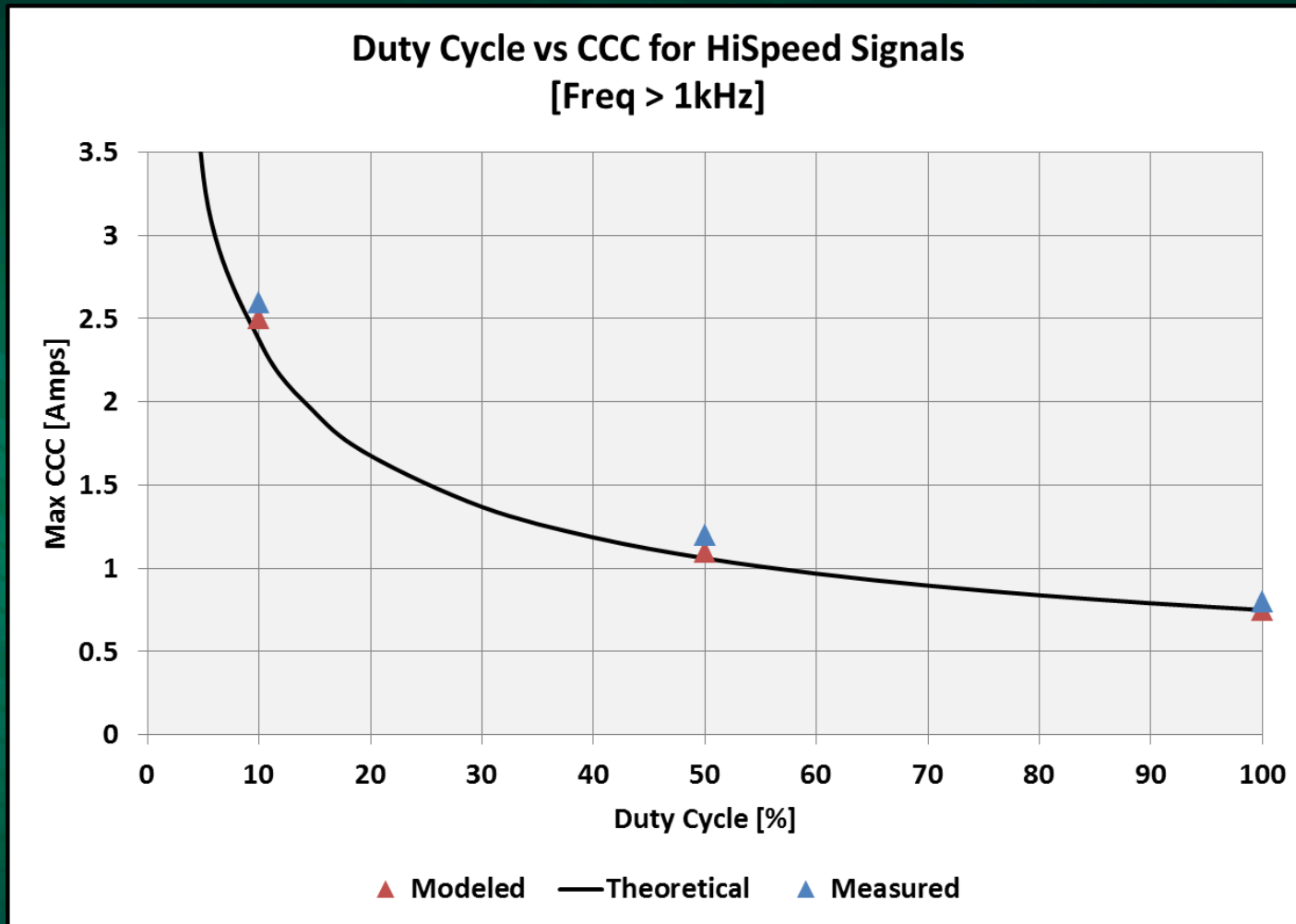
If we assume small  $\Delta T$  between pulses, CCC for any duty cycle should follow the equation:

$$CCC_{\downarrow HiSpeed} = \sqrt{CCC_{\downarrow ISMI}}$$





# Hi-Speed Signals: Results



- Simulation & Experimental tests closely follow theoretical equation for equivalent energy input
- Significant increase in CCC for Duty Cycles < 30%
- Behaves thermally like a DC input

$$CCC_{HiSpeed} = \sqrt{CC}$$



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# Intermediate Signals: Definition

- **Definition:**

- Consists of the remainder of signals that do not qualify to be either “isolated” or “Hi-Speed.”
- Time between events is such that the probe experiences large  $\Delta T$  & carries residual heat between pulses. ( $f = 10 \text{ Hz} - 1 \text{ kHz}$ ,  $T = 100\text{ms} - 1\text{ms}$ )

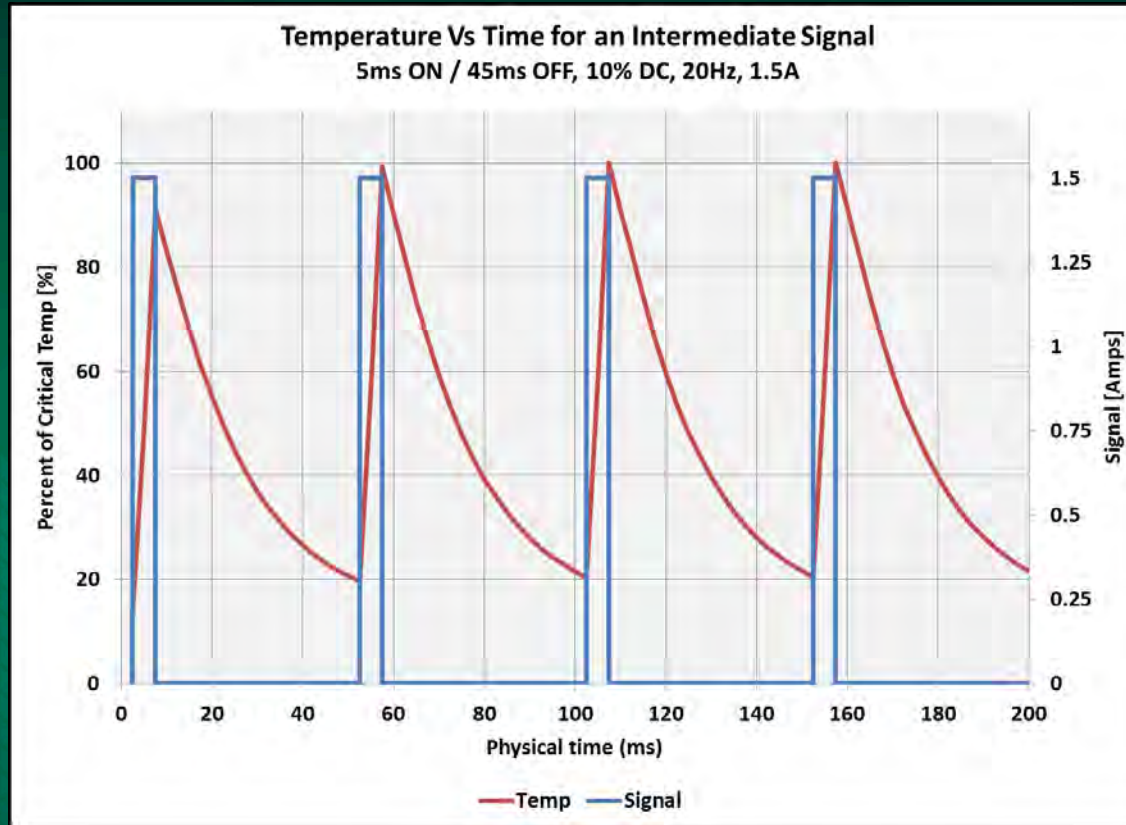
- **Most complex to analyze:**

- Temperature “walks upward” with each pulse, but at a rate unique to that signal condition & probe design.
- Number of pulses to reach steady-state can range from just a handful to several hundred

- **Thankfully these are the least likely signal types to be used on a probe card**



# Intermediate Signal: Results



- **This particular signal condition reaches steady-state in 3 cycles**
  - Max CCC for 5ms ON / 45ms OFF = 1.5 A
- **Intermediate signals will always have a lower CCC than the equivalent Isolated Pulse or Hi-Speed Signal**
  - 5ms pulse width for Isolated Pulse = 1.75 A
  - 10% Duty Cycle for Hi-Speed = 2.5 A





# Summary & Conclusion

- CCC can be greatly influenced by the specific signal used on a probe
- Shown that CCC of a probe can be increased by as much as 400% given the proper signal condition
- The CCC of any arbitrary signal can be modeled successfully using a multiphysics simulation software
- For vertical probe cards to continue to advance < 100um Pitch:
  - Probe card suppliers should better understand their CCC capabilities for unpredictable surges in current
  - Probe card customers can aid by providing as much information about the test conditions as possible
- Communication will become increasingly important for matching probe technology to product



# Future Work

- **Collect additional experimental data to continue to validate the multiphysics simulation**
- **Consider defining a CCC characterization test for isolated pulses**
  - Would need to better understand what a typical discharge event looks like
- **Increase overall robustness and value of simulation to account for any combination of:**
  - Heat from neighboring springs
  - Testing at elevated or reduced temperatures
  - Cres Variation
- **Allow FormFactor/MicroProbe to evaluate very quickly:**
  - Product Needs → Spring Design → Equivalent ISMI → Test → Ship

